ECE 305 - Fall 2015

Solutions for Exam 1– Friday, September 18, 2015

Part I: Multiple Choice

1. D

The next-nearest neighbors are located on the face of the cube associated with the crystalline silicon lattice. Relative to the origin, these faces are located at $(\frac{a}{2}, \frac{a}{2}, 0)$ or similar. Thus, the total distance will be $a/\sqrt{2}$. Since a = 5.43 Å, we obtain a value of approximately 3.85 Å.

2. D

The key equation sheet indicates $J_n = nq\mu_n \mathcal{E}_x + qD_n \frac{dn}{dx}$. To eliminate drift effects, we set $\mathcal{E}_x = 0$, which leaves us with $J_n = +qD_n \frac{dn}{dx}$.

3. E

Carrier mobility is limited by at least two types of scattering: charged impurity scattering, which decreases with temperature; and lattice (phonon) scattering, which increases with temperature. The best tradeoff between these two is found at a finite temperature that depend on material properties such as dopant concentration, often (but not always) creating a mobility peak between 50 K and 200 K.

4. B

Taking the inverse of the intercepts yields $(\frac{1}{2}, 1, \frac{1}{3})$. Multiplying each term by 6 yields the Miller index: (362).

5. B

The key equation sheet shows that $1/\rho = q(n\mu_n + p\mu_p)$. Since $N_D = 4.5 \times 10^{14} \text{ cm}^{-3}$, holes can be neglected, which implies $\rho \approx 1/(q\mu_n N_D)$. Plugging in the values provided ($\mu_n = 1400 \text{ cm}^2/\text{V}\cdot\text{s}$), we obtain $\rho \approx 10 \Omega \cdot \text{cm}$.

$$F(E 2_{3}S) = E \times R_{4n} I.$$

$$F = R + N_{b} - R_{h} = 0.$$

$$\Rightarrow P = \frac{1}{2} \begin{bmatrix} N_{h} + \sqrt{N_{h}^{2} + 4n_{h}} \end{bmatrix}$$

$$\Rightarrow [.0] \times 3_{2} \vee [0^{5} Cm^{-3}]$$

$$= 3_{.0}3_{.} \times 10^{3} Cm^{-1}$$

$$b. n = \frac{N_{1}^{5}}{P} = \frac{(3 \times 10^{10} Cm^{-1})^{2}}{3_{.0}3 \times 10^{3} Cm^{-1}} = 2.91 \times 10^{13} Cm^{-2}.$$

$$C. \int_{W} = n_{1}^{0} 4hE$$

$$I_{0} = P_{1}^{0} 4hE$$

$$I_{0} = 2.91 \times 10^{3} Cm^{-1} \times 1.0 \times 10^{7} C \times 8000 Cm^{2} V_{.5} \times 45 V_{cm} = 1.52 A/cm^{5}$$

$$I_{0} = N_{1} V e^{-\frac{1}{2}K_{0}} \times 1.0 \times 10^{7} C \times 400 Cm^{2} V_{.5} \times 45 V_{cm} = 7.76 A/cm^{5}$$

$$I_{0} = N_{1} V e^{-\frac{1}{2}K_{1}} = N_{1} V e^{-\frac{1}{E}} = \frac{1}{2} (3_{3} \times 10^{5} Cm^{-2}) e^{-\frac{1}{2} (224)} e^{-\frac{1}{2} N}$$

$$b. E_{F} = E_{2}, \quad S_{0} = P = W_{1} \frac{10^{10} Cm^{-2}}{\frac{10^{10} Cm^{-2}}{K_{0}}} = \frac{1}{2} S S C cm^{-3}$$

$$b. E_{F} = E_{2}, \quad S_{0} = P = W_{1} \frac{10^{10} Cm^{-2}}{10^{10} Cm^{-2}} = \frac{1}{1.0 \times 10^{10} Cm^{-3}}$$

$$V = \frac{E}{-\frac{1}{6}} + C_{2} \cdot \Lambda \approx 7_{0}, V = 0 \quad \text{for } -\frac{1}{\sqrt{3}} \qquad \text{big}(R_{0}) = \frac{1}{2} \log(h_{1}) + \frac{1}{23} \frac{E_{2} - E_{1}}{E_{1}}$$

$$= \log [E_{0}] < E_{1} C_{1}$$